## 2SC3052

FOR LOW FREQUENCY AMPLIFY APPLICATION SILICON NPN EPITAXIAL TYPE(mini type)

### **DESCRIPTION**

2SC3052 is a mini package resin sealed silicon NPN epitaxial transistor,

It is designed for low frequency voltage application.

## **FEATURE**

Small collector to emitter saturation voltage.

VCE(sat)=0.3V max(@Ic=100mA,IB=10mA)

Excellent linearity of DC forward gain.

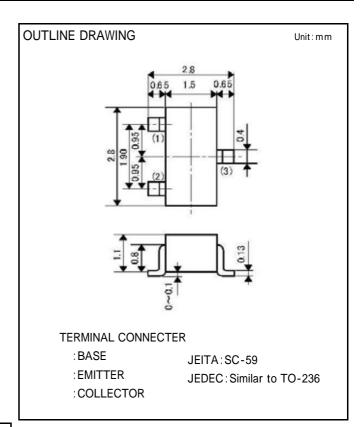
Super mini package for easy mounting

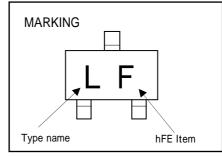
## **APPLICATION**

For Hybrid IC,small type machine low frequency voltage Amplify application.

## MAXIMUM RATINGS (Ta=25 )

Symbol	Parameter	Ratings	Unit
$V_{CBO}$	Collector to Base voltage	50	V
$V_{CEO}$	Collector to Emitter voltage	50	V
$V_{EBO}$	Emitter to Base voltage	6	V
Ιo	Collector current	200	mA
P <sub>c</sub>	Collector dissipation	200	mW
$T_j$	Junction temperature	+ 150	
T <sub>stg</sub>	Storage temperature	-55 ~ + 150	
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## ELECTRICAL CHARACTERISTICS (Ta=25 )

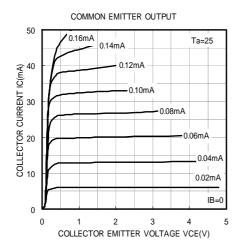
Parameter	Symbol	Test conditions	Limits			Unit
Farameter	Symbol		Min	Тур	Max	Offic
C to E break down voltage	V(BR)CEO	I <sub>C</sub> =100 μ A ,R <sub>BE</sub> =	50	-	-	V
Collector cut off current	ICBO	V <sub>CB</sub> =50V, I <sub>E</sub> =0mA	-	-	0.1	μА
Emitter cut off current	IEBO	$V_{EB}$ =6V, $I_{C}$ =0mA	-	-	0.1	μΑ
DC forward current gain	hFE	V <sub>CE</sub> =6V, I <sub>C</sub> =1mA	150	-	500	
DC forward current gain	hFE	$V_{CE}$ =6 $V$ , $I_{C}$ =0.1 $m$ A	90	-	-	
C to E Saturation Vlotage	VCE(sat)	I <sub>C</sub> =100mA ,I <sub>B</sub> =10mA	-	-	0.3	V
Gain bandwidth product	fT	V <sub>CE</sub> =6V, I <sub>E</sub> =-10mA	-	200	-	MHz
Collector output capacitance	Cob	V <sub>CB</sub> =6V, I <sub>E</sub> =0,f=1MHz	-	2.5	-	pF
Noise figure	NF	V <sub>CE</sub> =6V, I <sub>E</sub> =-0.1mA,f=1kHz,RG=2k	-	-	15	dB

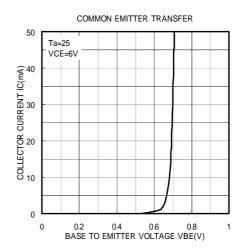
) It shows hFE classification at right table.

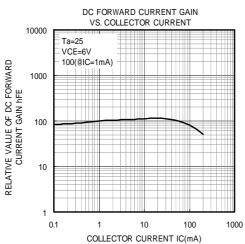
Item	E	F	
hFE Item	150 ~ 300	250 ~ 500	

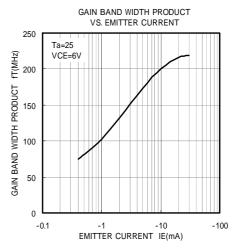
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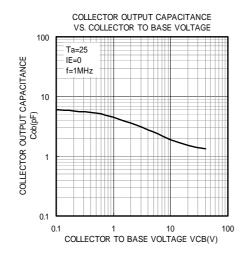
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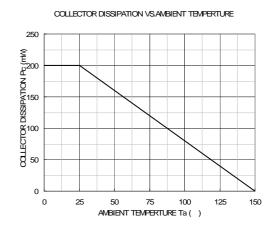






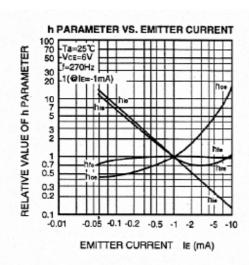


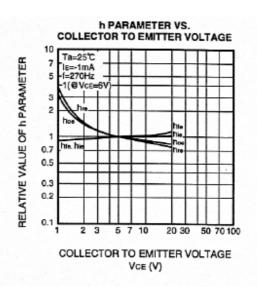




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## COMMON EMITTER h PARAMETER (TYPICAL VALUE)

Symbol	Parameter	Test conditions	Limits	Unit
hie	Closed loop small signal input impedance	Ta=25℃	8.5	kΩ
hre	Open loop small signal reverse voltage amplification factor	VCE=6V	0.1	×10-3
hte	Closed loop small signal forward current amplification factor	IE=-1mA	300	
hoe	Open loop small signal output admittance	1=270Hz	5.5	μS



6-41 Tsukuba, Isahaya, Nagasaki, 854-0065 Japan

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